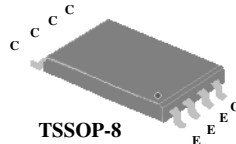
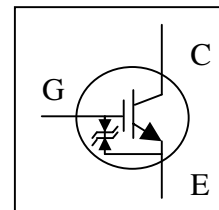




- ▼  $I_{CP}=150A @V_{GE}=3.0V$
- ▼ Low Gate Drive
- ▼ Strobe Flash Applications
- ▼ RoHS Compliant & Halogen-Free



$V_{CE}$	400V
$I_{CP}$	150A



**Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
$V_{CE}$	Collector-Emitter Voltage	400	V
$V_{GEP}$	Peak Gate-Emitter Voltage	$\pm 6$	V
$I_{CP}$	Pulsed Collector Current, $V_{GE} @ 3.0V$	150	A
$P_D @ T_A=25^\circ C^1$	Maximum Power Dissipation	1	W
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ C$
$T_J$	Junction Temperature Range	-55 to 150	$^\circ C$

**Electrical Characteristics@ $T_J=25^\circ C$ (unless otherwise specified)**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$I_{GES}$	Gate-Emitter Leakage Current	$V_{GE}=\pm 6V, V_{CE}=0V$	-	-	$\pm 30$	$\mu A$
$I_{CES}$	Collector-Emitter Leakage Current	$V_{CE}=400V, V_{GE}=0V$	-	-	10	$\mu A$
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{GE}=3V, I_{CP}=150A$ (Pulsed)	-	5.5	9	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{CE}=V_{GE}, I_C=1mA$	0.3	-	1.2	V
$Q_g$	Total Gate Charge	$I_C=40A$	-	60	96	nC
$Q_{ge}$	Gate-Emitter Charge	$V_{CE}=200V$	-	6	-	nC
$Q_{gc}$	Gate-Collector Charge	$V_{GE}=4V$	-	25	-	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{CC}=320V$	-	200	-	ns
$t_r$	Rise Time	$I_C=150A$	-	900	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=10\Omega$	-	800	-	ns
$t_f$	Fall Time	$V_{GE}=3V$	-	650	-	ns
$C_{ies}$	Input Capacitance	$V_{GE}=0V$	-	4140	-	pF
$C_{oes}$	Output Capacitance	$V_{CE}=30V$	-	30	-	pF
$C_{res}$	Reverse Transfer Capacitance	$f=1.0MHz$	-	20	-	pF
$R_{thJA}^1$	Thermal Resistance Junction-Ambient		-	-	125	$^\circ C/W$

**Notes:**

1.Surface mounted on 1 in<sup>2</sup> copper pad of FR4 board, t=10s.

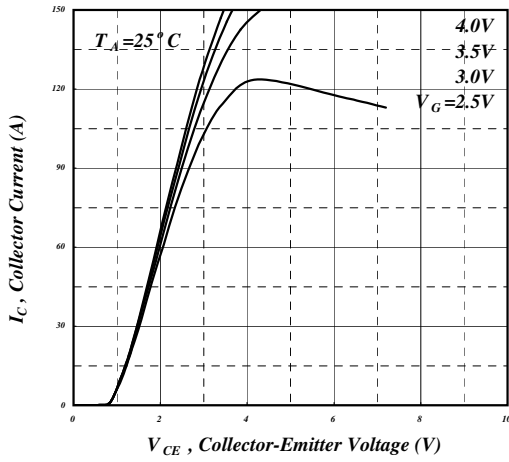


Fig 1. Typical Output Characteristics

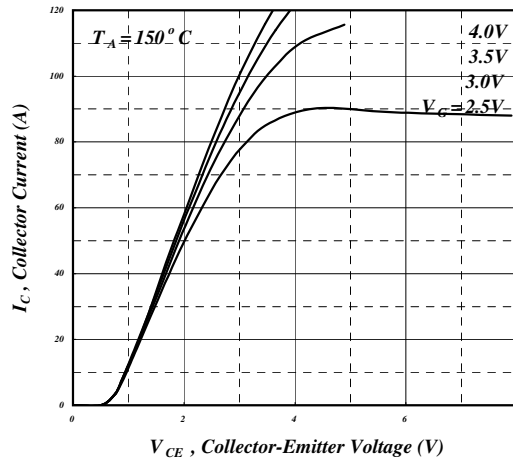


Fig 2. Typical Output Characteristics

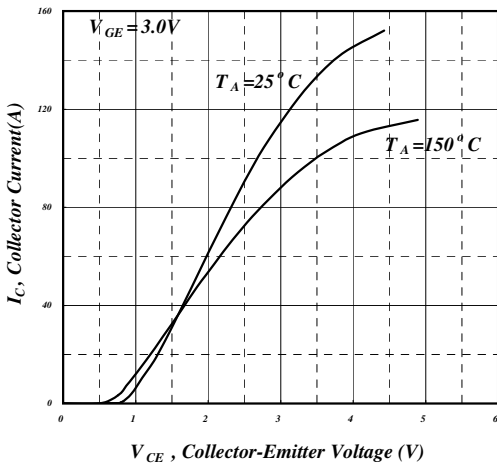


Fig 3. Typical Saturation Voltage Characteristics

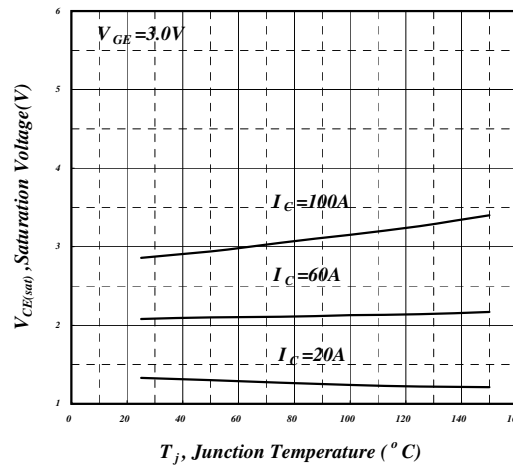


Fig 4. Collector- Emitter Saturation Voltage v.s. Junction Temperature

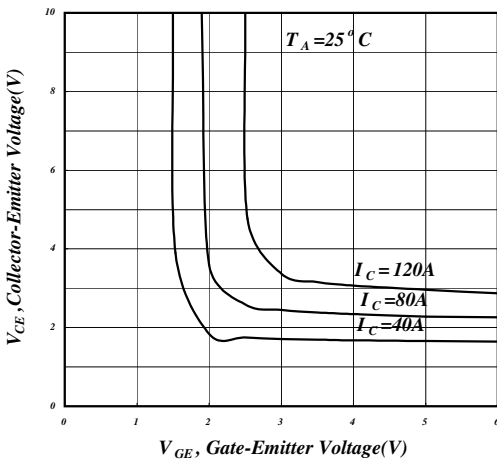


Fig 5. Collector Current v.s. Gate-Emitter Voltage

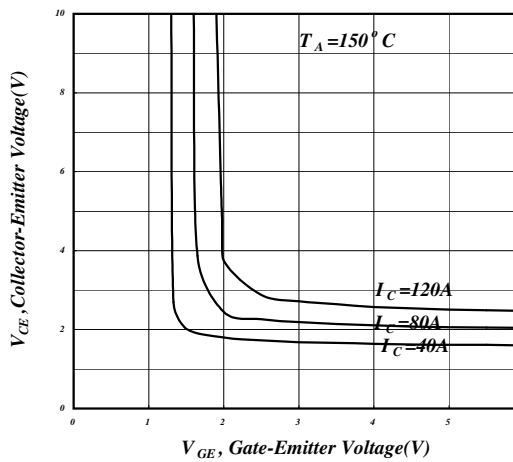


Fig 6. Collector Current v.s. Gate-Emitter Voltage

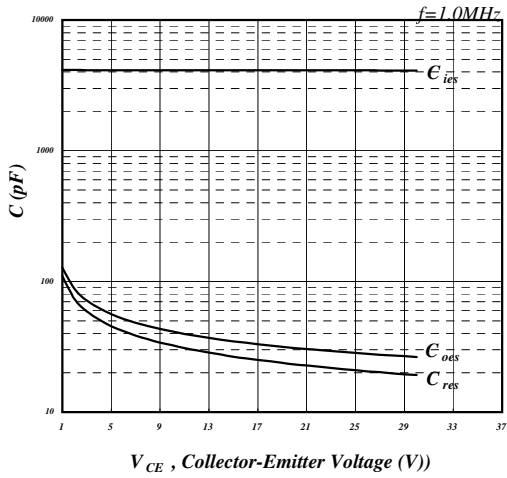


Fig 7. Typical Capacitance Characteristics

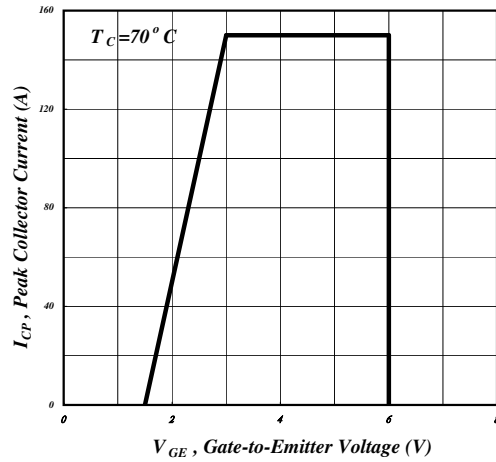


Fig 8. Maximum Pulse Collector Current

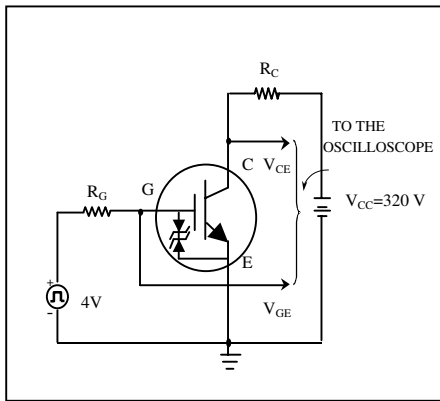


Fig 9. Switching Time Test Circuit

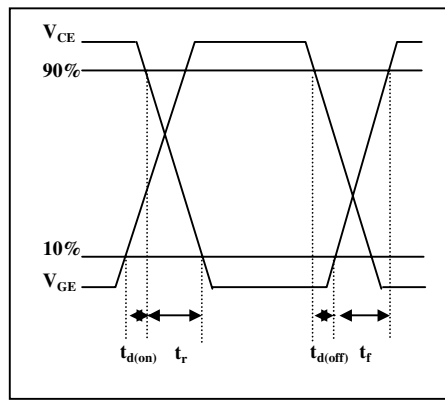


Fig 10. Switching Time Waveform

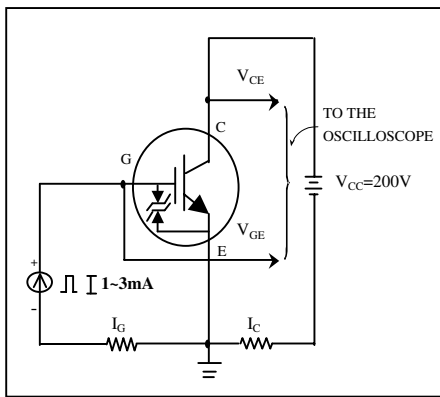


Fig 11. Gate Charge Test Circuit

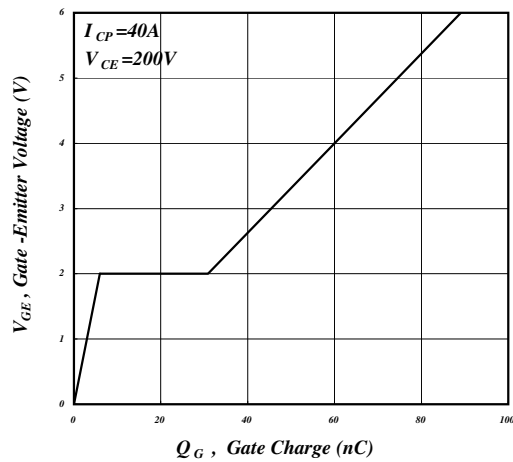


Fig 12. Gate Charge Waveform